

BD435, BD437, BD439, BD441

Plastic Medium Power Silicon NPN Transistor

This series of plastic, medium-power silicon NPN transistors can be used for amplifier and switching applications. Complementary types are BD438 and BD442.

Features

- Pb-Free Package is Available*



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4.0 AMPERES POWER TRANSISTORS NPN SILICON

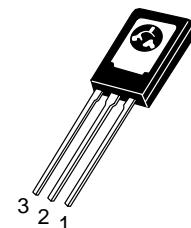
MAXIMUM RATINGS

| Rating | | Symbol | Value | Unit |
|--|----------------------------------|----------------|----------------------|------------------------------------|
| Collector-Emitter Voltage | BD435 BD437 BD439 BD441 | V_{CEO} | 32 45 60 80 | Vdc |
| Collector-Base Voltage | BD435 BD437 BD439 BD441 | V_{CBO} | 32 45 60 80 | Vdc |
| Emitter-Base Voltage | | V_{EBO} | 5.0 | Vdc |
| Collector Current | | I_C | 4.0 | Adc |
| Base Current | | I_B | 1.0 | Adc |
| Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C | | P_D | 36 288 | Watts $\text{W}/^\circ\text{C}$ |
| Operating and Storage Junction Temperature Range | | T_J, T_{stg} | -55 to +150 | °C |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

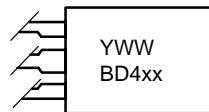
THERMAL CHARACTERISTICS

| Characteristic | | Symbol | Max | Unit |
|--------------------------------------|--|---------------|-----|------|
| Thermal Resistance, Junction-to-Case | | θ_{JC} | 3.5 | °C/W |



TO-225AA
CASE 77
STYLE 1

MARKING DIAGRAM



xx = 35, 37, 39, 41
Y = Year
WW = Work Week

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|--------|-----------------------|-----------------------|
| BD435 | TO-225AA | 500 Units/Box |
| BD437 | TO-225AA | 500 Units/Box |
| BD437G | TO-225AA (Pb-Free) | 500 Units/Box |
| BD437T | TO-225AA | 500 Units/Rail |
| BD439 | TO-225AA | 500 Units/Box |
| BD441 | TO-225AA | 500 Units/Box |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERMM/D.

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ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|--|-----------------------------|----------------------------------|----------------------|------------------|--------------------------|
| Collector-Emitter Breakdown Voltage ($I_C = 100 \text{ mA}, I_B = 0$) | $V_{(\text{BR})\text{CEO}}$ | 32 45 60 80 | — — — — | — — — — | Vdc |
| Collector-Base Breakdown Voltage ($I_C = 100 \mu\text{A}, I_B = 0$) | $V_{(\text{BR})\text{CBO}}$ | 32 45 60 80 | — — — — | — — — — | Vdc |
| Emitter-Base Breakdown Voltage ($I_E = 100 \mu\text{A}, I_C = 0$) | $V_{(\text{BR})\text{EBO}}$ | 5.0 | — | — | Vdc |
| Collector Cutoff Current ($V_{CB} = 32 \text{ V}, I_E = 0$) ($V_{CB} = 45 \text{ V}, I_E = 0$) ($V_{CB} = 60 \text{ V}, I_E = 0$) ($V_{CB} = 80 \text{ V}, I_E = 0$) | I_{CBO} | BD435 BD437 BD439 BD441 | — — — — | — — — — | 0.1 0.1 0.1 0.1 |
| Emitter Cutoff Current ($V_{EB} = 5.0 \text{ V}$) | I_{EBO} | — | — | 1.0 | mAdc |
| DC Current Gain ($I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$) | h_{FE} | BD435 BD437 BD439 BD441 | 40 30 20 15 | — — — — | — — — — |
| DC Current Gain ($I_C = 500 \text{ mA}, V_{CE} = 1.0 \text{ V}$) | h_{FE} | BD435 BD437 BD439, BD441 | 85 85 40 | — — — | 475 375 475 |
| DC Current Gain ($I_C = 2.0 \text{ A}, V_{CE} = 1.0 \text{ V}$) | h_{FE} | BD435 BD437 BD439 BD441 | 50 40 25 15 | — — — — | — — — — |
| Collector Saturation Voltage ($I_C = 2.0 \text{ A}, I_B = 0.2 \text{ V}$) ($I_C = 3.0 \text{ A}, I_B = 0.3 \text{ A}$) | $V_{CE(\text{sat})}$ | BD435 BD437, BD439, BD441 | — — | — — | 0.5 0.8 |
| Base-Emitter On Voltage ($I_C = 2.0 \text{ A}, V_{CE} = 1.0 \text{ V}$) | $V_{BE(\text{on})}$ | — | — | 1.1 | Vdc |
| Current-Gain – Bandwidth Product ($V_{CE} = 1.0 \text{ V}, I_C = 250 \text{ mA}, f = 1.0 \text{ MHz}$) | f_T | 3.0 | — | — | MHz |

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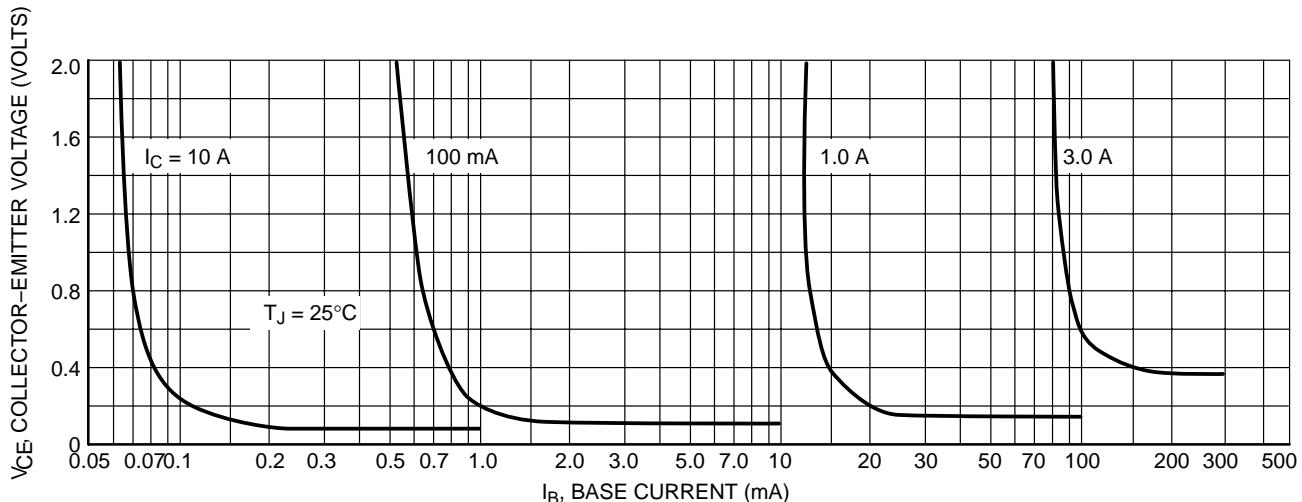


Figure 1. Collector Saturation Region

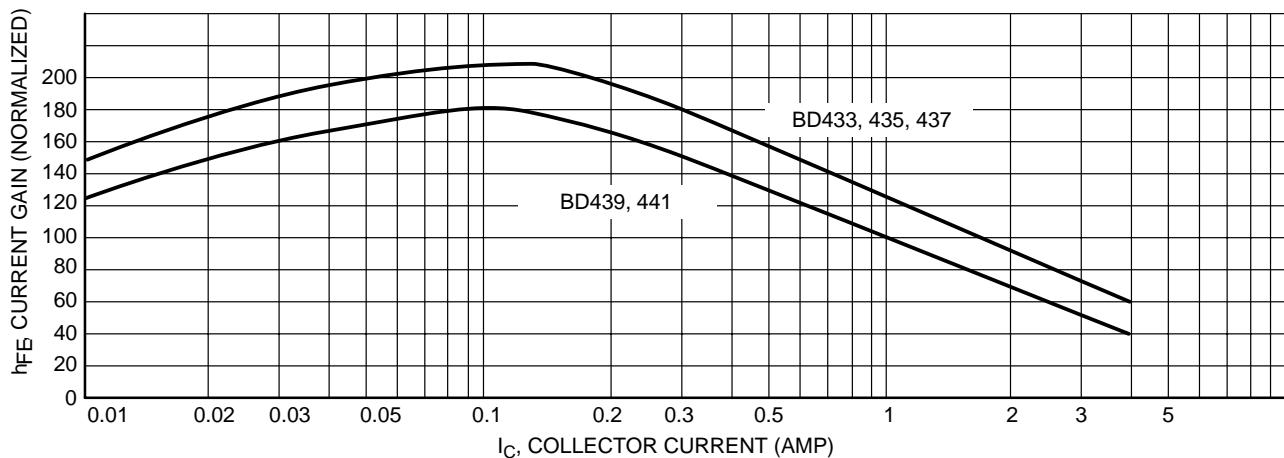


Figure 2. Current Gain

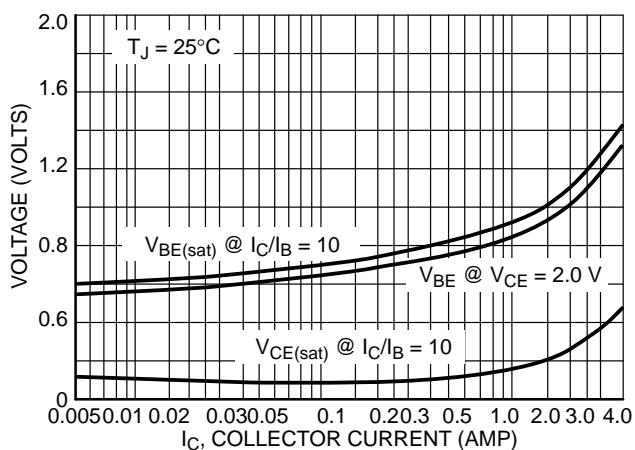


Figure 3. "On" Voltage

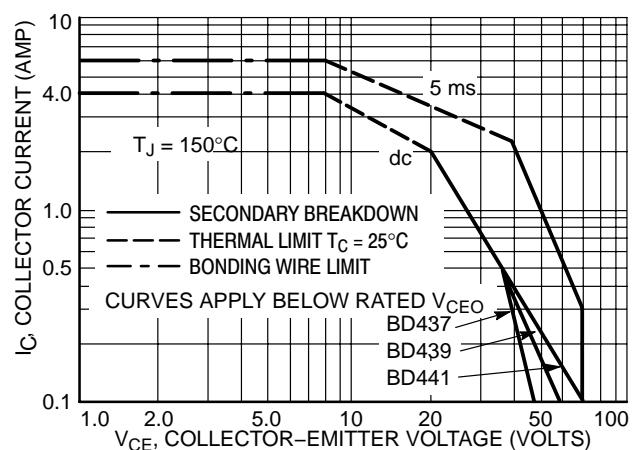
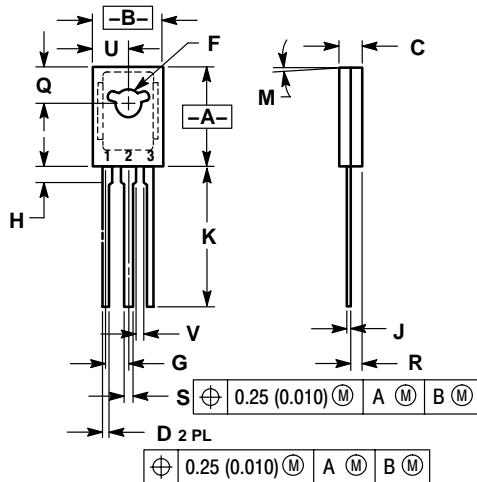


Figure 4. Active Region Safe Operating Area

BD435, BD437, BD439, BD441

PACKAGE DIMENSIONS

TO-225AA
CASE 77-09
ISSUE Z



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 077-01 THRU -08 OBSOLETE, NEW STANDARD 077-09.

| DIM | INCHES | | MILLIMETERS | |
|-----|--------|-------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.425 | 0.435 | 10.80 | 11.04 |
| B | 0.295 | 0.305 | 7.50 | 7.74 |
| C | 0.095 | 0.105 | 2.42 | 2.66 |
| D | 0.020 | 0.026 | 0.51 | 0.66 |
| F | 0.115 | 0.130 | 2.93 | 3.30 |
| G | 0.094 | BSC | 2.39 | BSC |
| H | 0.050 | 0.095 | 1.27 | 2.41 |
| J | 0.015 | 0.025 | 0.39 | 0.63 |
| K | 0.575 | 0.655 | 14.61 | 16.63 |
| M | 5° TYP | | 5° TYP | |
| Q | 0.148 | 0.158 | 3.76 | 4.01 |
| R | 0.045 | 0.065 | 1.15 | 1.65 |
| S | 0.025 | 0.035 | 0.64 | 0.88 |
| U | 0.145 | 0.155 | 3.69 | 3.93 |
| V | 0.040 | --- | 1.02 | --- |

STYLE 1:

1. Emitter
2. Collector
3. Base

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